PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of: Wonju CHO, et al.

Serial No.: New Application Group Art Unit: Not Yet Assigned

Filed: October 15, 2001 Examiner: Not Yet Assigned

Title: ULTRA SMALL SIZE VERTICAL MOSFET DEVICE AND METHOD FOR

THE MANUFACTURE THEREOF

INFORMATION DISCLOSURE STATEMENT

Honorable Commissioner for Patents Washington, DC 20231

October 15, 2001

Sir:

As a means of complying with the duty of disclosure under 37 CFR \$1.56, and in accordance with 37 CFR \$\$1.97 and 1.98, Applicant(s), through the undersigned attorney, submits this Information Disclosure Statement. The patents, publications or other information submitted herewith are listed on the attached Form PTO-1449 and copies are attached.

In accordance with 37 CFR \$1.97(b)(1) or (2), this Information Disclosure Statement is being filed either within three months of the filing date of the above-identified application, or within three months of the date of entry into the national stage of the above-identified application as set forth in 37 CFR \$1.491. Accordingly, no fee is required.

Respectfully submitted,

JACOBSON HOLMAN, PLLC

By:							_	
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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT

ATTY. D SERIAL APPLICA	NO.:	***************************************	USO t Assigned CHO, et al.	FILING	ART UNIT:_) DATE: Octo S DATE: Oc	ober 15	, 2001				
*****	*****	******		******	*****	*****	*****				
*EXAMINER INITIAL		DOCUMENT NUMBER	DATE	ATENT DOCUMENTS NAME	INT'L CLASS	SUB- CLASS	FILING DATE (If Appropriate)				
	AA	5,365,097	11/15/94	Kenney	<u> H01L</u>	29/68	10/05/92				
	AB	5,382,816	01/17/95	Mitsui	H01L	29/10	05/28/93				
	AC		-				·				
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		DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION (YES) (NO)				
	AD .		-								
	ΑE			-							

	AF			The Vertical Re E; p.99-75 - 99-		Gate (VI	RG) MOSFET:				
	AG	Hergenrother, et al.; The Vertical Replacement-Gate (VRG) MOSFET With; 2000 Extended Abstract of; p. 220-221.									
	AH				·						
EXAMINER				DATE CONSIDERED							

^{*} EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant(s).